

Features

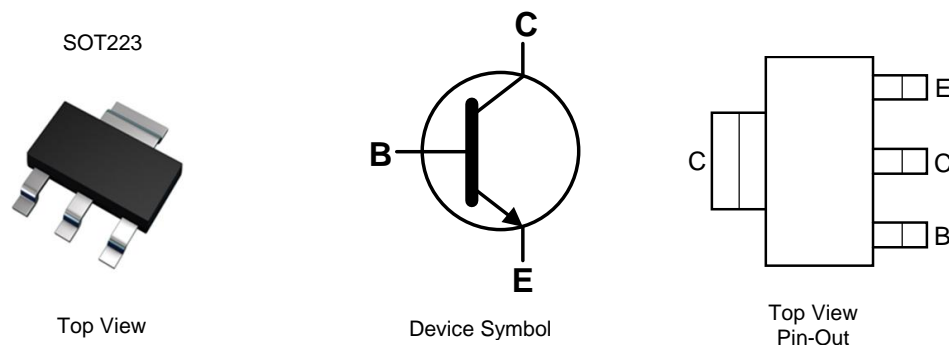
- $BV_{CEX} > 100V$
- $BV_{CEO} > 20V$
- $BV_{ECO} > 6V$
- $I_C = 7A$ High Continuous Current
- Low Saturation Voltage $V_{CE(sat)} < 48mV @ 1A$
- $R_{CE(sat)} = 31m\Omega$
- Complementary PNP Type: ZXTP25020DG
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 Ⓔ③
- Weight: 0.112 grams (Approximate)

Applications

- DC-DC Converters
- Motor Drive
- Relay, Lamp and Solenoid Drive
- Regulator Circuits

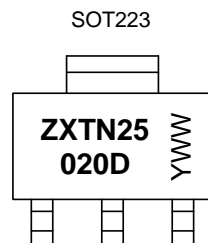


Ordering Information (Notes 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|------------|------------|--------------------|-----------------|-------------------|
| ZXTN25020DGTA | AEC-Q101 | ZXTN25020D | 7 | 12 | 1,000 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZXTN25020D = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------|------|
| Collector-Base Voltage | V _{CB0} | 100 | V |
| Collector-Emitter Voltage (forward blocking) | V _{CEX} | 100 | V |
| Collector-Emitter Voltage | V _{CEO} | 20 | V |
| Emitter-Collector Voltage (reverse blocking) | V _{ECO} | 6 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | I _C | 7 | A |
| Base Current | I _B | 1 | A |
| Peak Pulse Current | I _{CM} | 15 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

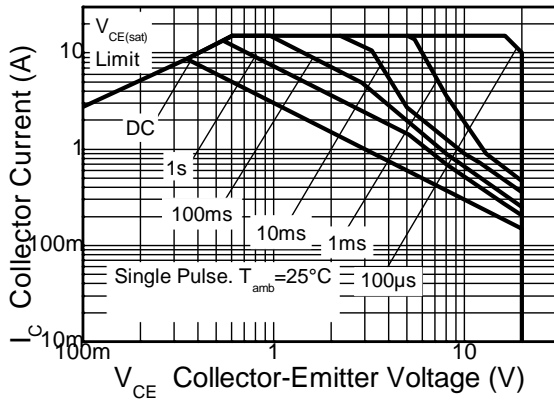
| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------------|
| Power Dissipation Linear Derating Factor | P _D | 1.2 | W mW/°C |
| | | 9.6 | |
| | | 1.6 | |
| | | 12.8 | |
| | | 3 | |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 24 | °C/W |
| | | 5.3 | |
| | | 42 | |
| | | 104 | |
| Thermal Resistance, Junction to Lead | R _{θJL} | 16 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 10)

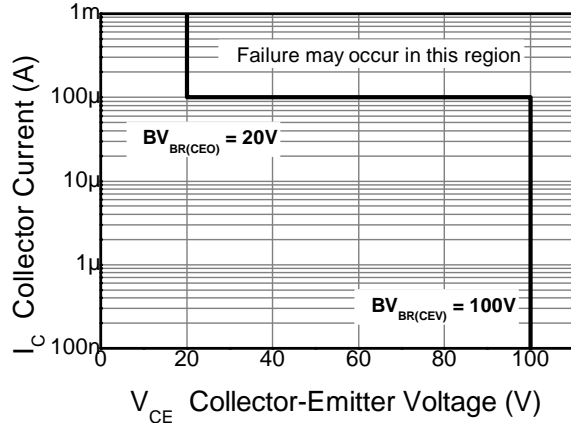
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 - Same as Note 7 measured at t<5 seconds.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

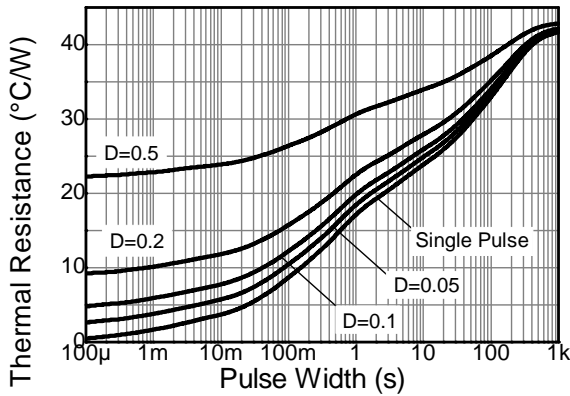
Thermal Characteristics and Derating Information (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



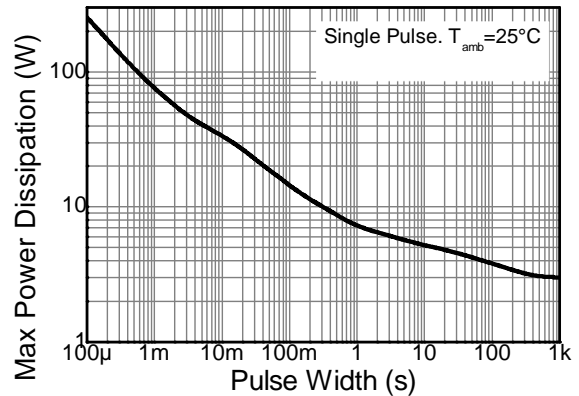
Safe Operating Area



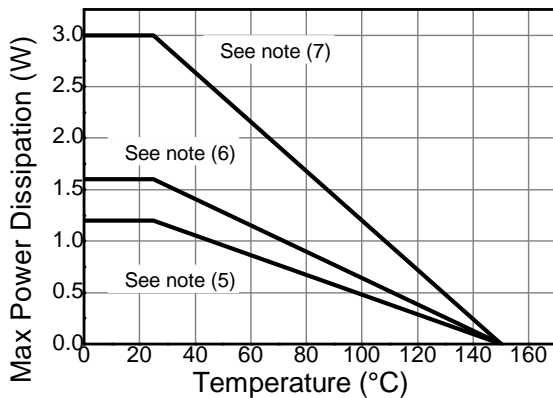
Safe Operating Area



Transient Thermal Impedance



Pulse Power Dissipation



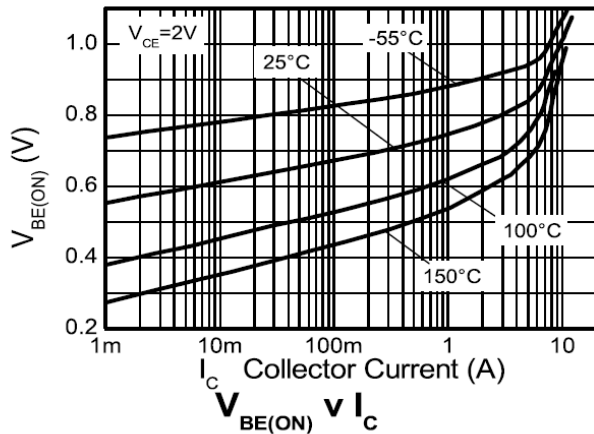
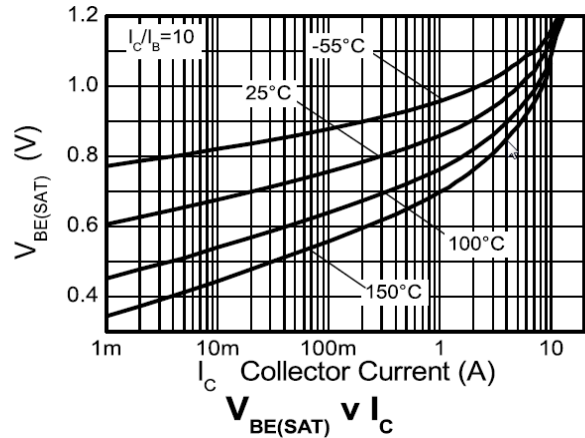
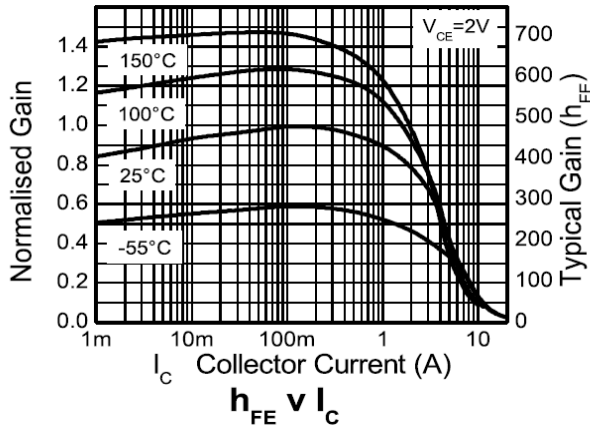
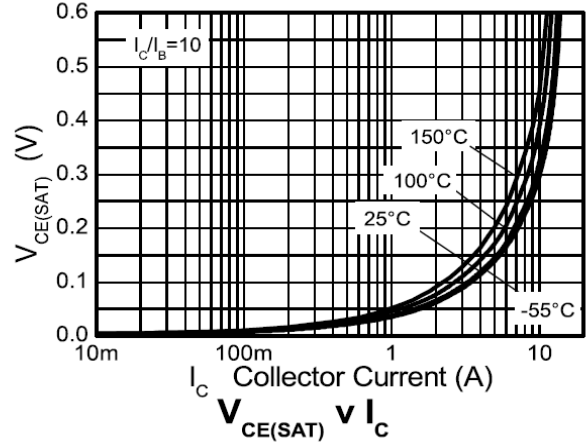
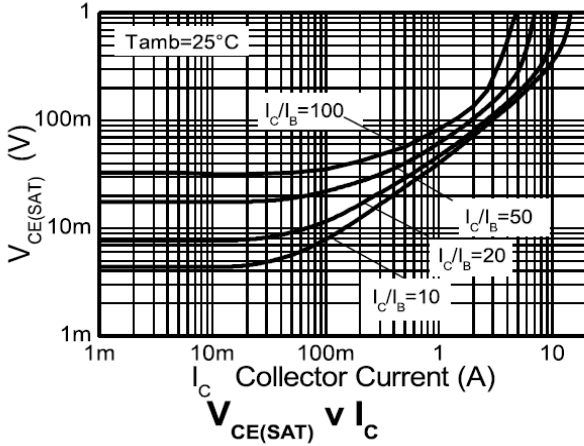
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|-----|-------|-------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 100 | 125 | – | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage (forward blocking) | BV _{CEX} | 100 | 120 | – | V | I _C = 100μA, R _{BE} <1kΩ or -1V < V _{BE} > 0.25V |
| Collector-Emitter Breakdown Voltage (Note 11) | BV _{CEO} | 20 | 35 | – | V | I _C = 10mA |
| Emitter-Collector Breakdown Voltage (reverse blocking) | BV _{ECX} | 6 | 8.3 | – | V | I _E = 100μA, R _{BC} <1kΩ or 0.25V < V _{BC} > -0.25V |
| Emitter-Collector Breakdown Voltage (reverse blocking) | BV _{ECO} | 5 | 6.1 | – | V | I _E = 100μA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | 8.3 | – | V | I _E = 100μA |
| Collector Cut-Off Current | I _{CBO} | – | < 1 | 50 | nA | V _{CB} = 100V |
| | | – | – | 0.5 | μA | V _{CB} = 100V, T _A = 100°C |
| Collector-Emitter Cut-Off Current | I _{CEX} | – | – | 100 | nA | V _{CE} = 100V, R _{BE} <1kΩ or -1V < V _{BE} > 0.25V |
| Emitter Cut-Off Current | I _{EBO} | – | < 1 | 50 | nA | V _{EB} = 5.6V |
| Collector-Emitter Saturation Voltage (Note 11) | V _{CE(sat)} | – | 40 | 48 | mV | I _C = 1A, I _B = 100mA |
| | | – | 60 | 75 | mV | I _C = 1A, I _B = 20mA |
| | | – | 100 | 120 | mV | I _C = 2A, I _B = 40mA |
| | | – | 130 | 180 | mV | I _C = 2A, I _B = 20mA |
| | | – | 225 | 290 | mV | I _C = 7A, I _B = 700mA |
| Base-Emitter Saturation Voltage (Note 11) | V _{BE(sat)} | – | 1,090 | 1,150 | mV | I _C = 7A, I _B = 700mA |
| Base-Emitter Turn-On Voltage (Note 11) | V _{BE(on)} | – | 950 | 1,050 | mV | I _C = 7A, V _{CE} = 2V |
| DC Current Gain (Note 11) | h _{FE} | 300 | 450 | 900 | – | I _C = 10mA, V _{CE} = 2V |
| | | 250 | 360 | – | – | I _C = 2A, V _{CE} = 2V |
| | | 50 | 85 | – | – | I _C = 7A, V _{CE} = 2V |
| | | – | 15 | – | – | I _C = 15A, V _{CE} = 2V |
| Current Gain-Bandwidth Product (Note 11) | f _T | – | 215 | – | MHz | V _{CE} = 10V, I _C = 50mA, f = 100MHz |
| Input Capacitance (Note 11) | C _{ibo} | – | 152 | – | pF | V _{EB} = 0.5V, f = 1MHz |
| Output Capacitance (Note 11) | C _{obo} | – | 16.5 | 25 | pF | V _{CB} = 10V, f = 1MHz |
| Delay Time | t _d | – | 67.7 | – | ns | I _C = 1A, V _{CC} = 10V, I _{B1} = -I _{B2} = 10mA |
| Rise Time | t _r | – | 72.2 | – | ns | |
| Storage Time | t _s | – | 361 | – | ns | |
| Fall Time | t _f | – | 63.9 | – | ns | |

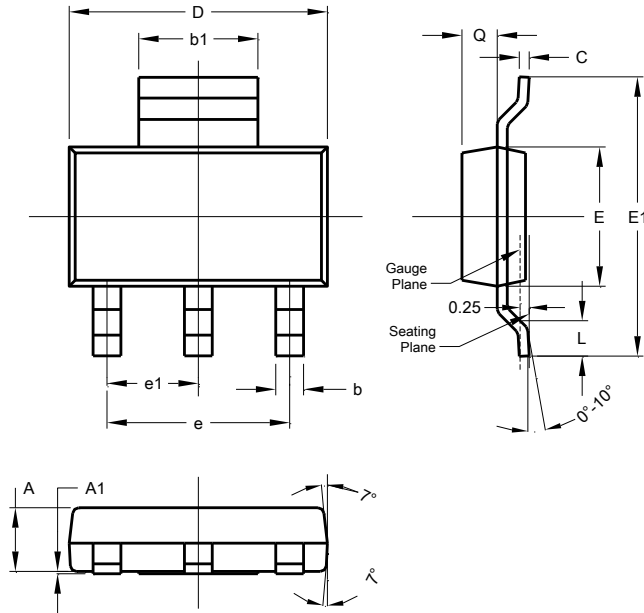
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

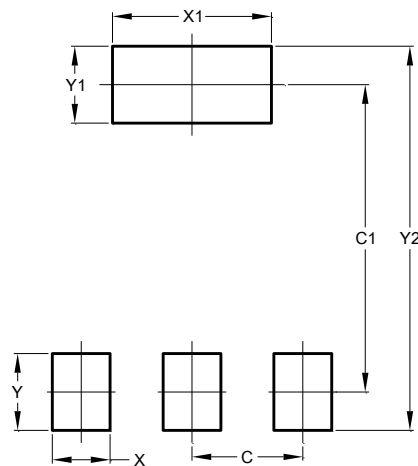
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT223 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 1.55 | 1.65 | 1.60 |
| A1 | 0.010 | 0.15 | 0.05 |
| b | 0.60 | 0.80 | 0.70 |
| b1 | 2.90 | 3.10 | 3.00 |
| C | 0.20 | 0.30 | 0.25 |
| D | 6.45 | 6.55 | 6.50 |
| E | 3.45 | 3.55 | 3.50 |
| E1 | 6.90 | 7.10 | 7.00 |
| e | - | - | 4.60 |
| e1 | - | - | 2.30 |
| L | 0.85 | 1.05 | 0.95 |
| Q | 0.84 | 0.94 | 0.89 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 2.30 |
| C1 | 6.40 |
| X | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |

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